NSN 5962-01-480-7507

Memory Microcircuit - Page 1 of 1



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# Maximum Power Dissipation Rating:

1.2 watts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **End Application:**

C141 awcfs gp

## **Features Provided:**

Ultraviolet erasable and monolithic

# Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

### Input Circuit Pattern:

22 input

### **Product Name:**

Microcircuit, digital, memory, cmos, uv erasable-programming, logic array

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# **Time Rating Per Chacteristic:**

25.00 nanoseconds af output megawatts

### Memory Device Type:

Pal

### **Special Features:**

This item shall be made from an unprogrammed device in accordance with smd specifications 5962-8872401lx

### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

24 printed circuit

## Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

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